Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK3756

VHF- and UHF-band Amplifier Applications

(Note)The TOSHIBA products listed in this document are intended for high frequency Power Amplifier of telecommunications equipment. These TOSHIBA products are neither intended nor warranted for any other use. Do not use these TOSHIBA products listed in this document except for high frequency Power Amplifier of telecommunications equipment.

• Output power: Po =32dBmW (typ)

• Gain: GP = 12dB (typ)

• Drain efficiency: $\eta_D = 60\%$ (typ)

Maximum Ratings (Ta = 25°C)

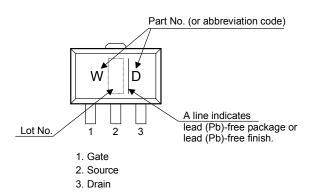
Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	7.5	٧
Gain-source voltage	V _{GSS} (Note 1)	3	V
Drain current	ΙD	1	Α
Power dissipation	P _D (Note 2)	3	W
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-45~150	°C

Note 1: Recommended Opelation Condition: 0~3V

Note 2: Tc = 25°C (When mounted on a 0.8 mm glass epoxy PCB)

1. GATE 2. SOURCE 3. DRAIN JEDEC JEITA 4.6MAX. 1.6MAX. 0.4±0.05 0.4±0.05 0.4±0.05 1.5±0.1 1.5±0.1 1.5±0.1 1.5±0.1 1.5±0.1 1.5±0.1 1.5±0.1 1.5±0.1

Marking



Caution: This device is sensitive to electrostatic discharge.

Please make enough tool and equipment earthed when you handle.

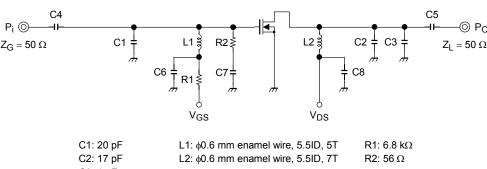
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output power	Po	V _{DS} = 4.5 V, lidle = 200 mA (V _{GS} = adjust),	31	32	_	dBmW
Drain efficiency	η_{D}		50	60	_	%
Power gain	G _P	$f = 470 \text{ MHz}, P_i = 20 \text{dBmW},$	_	12	_	dB
Threshold voltage	V _{th}	$V_{DS} = 4.5 \text{ V}, I_D = 0.5 \text{ mA}$	_	0.95	1.45	V
Drain cut-off current	I _{DSS}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}$	_	_	10	μΑ
Gate-source leakage current	I _{GSS}	$V_{GS} = 3 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	5	μА
Load Mismatch (Note 3)	_	$\begin{split} &V_{DS}=4.5~\text{V, f}=470~\text{MHz,}\\ &P_i=20\text{dBmW,}\\ &P_o=31\text{dBmW (V}_{GS}=\text{adjust),}\\ &\text{VSWR LOAD 10:1 all phase} \end{split}$	No Degradation		_	

Note 3: These characteristic values are measured using measurement tools specified by Toshiba.

Output Power Test Fixture

(Test Condition: f = 470 MHz, $V_{DS} = 4.5 \text{ V}$, $I_{idle} = 200 \text{ mA}$, $P_i = 20 \text{ dBmW}$)

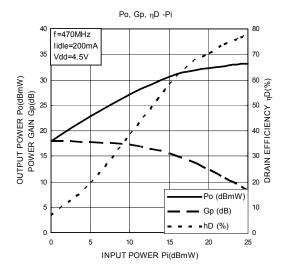


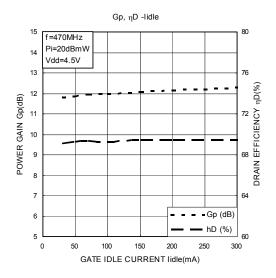
2

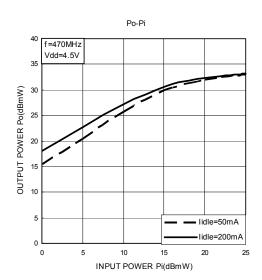
C3: 1 pF C4: 2200 pF Line: 2mm

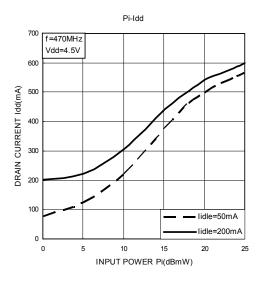
C5: 2200 pF C6: 10000 pF C7: 2200 pF C8: 10000 pF

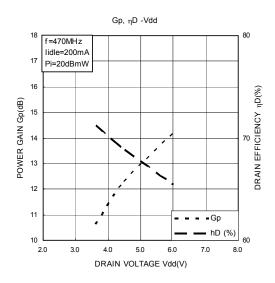
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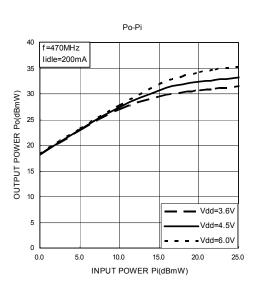


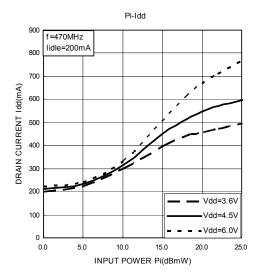












Note 4: These are only typical curves and devices are not necessarily guaranteed at these curves.

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